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RoHS

COMPLIANT

High Performance Schottky Rectifier, 2 A





SMA (DO-214AC)

LINKS TO ADDITIONAL RESOURCES



PRIMARY CHARACTERISTICS				
I _{F(AV)}	2 A			
V _R	100 V			
V _F at I _F	0.72 V			
I _{RM} max.	1 mA at 125 °C			
T _J max.	150 °C			
E _{AS}	1.0 mJ			
Package	SMA (DO-214AC)			
Circuit configuration	Single			

FEATURES

- · Small foot print, surface mountable
- Low forward voltage drop
- High frequency operation
- · Guard ring for enhanced ruggedness and long term reliability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Designed and qualified for industrial level
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

DESCRIPTION

The VS-20MQ100NTRPbF surface mount Schottky rectifier has been designed for applications requiring low forward drop and very small foot prints on PC boards. Typical applications are in disk drives, switching converters, freewheeling diodes, power supplies, battery charging, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS							
SYMBOL	CHARACTERISTICS	CHARACTERISTICS VALUES UNITS					
I _{F(AV)}	Rectangular waveform	2	A				
V _{RRM}		100	V				
I _{FSM}	t _p = 5 μs sine	120	А				
V _F	2 A _{pk} , T _J = 125 °C	0.72	V				
TJ	Range	-55 to +150	٥C				

VOLTAGE RATINGS			
PARAMETER	SYMBOL	VS-20MQ100NTRPbF	UNITS
Maximum DC reverse voltage	V _R	100	V
Maximum working peak reverse voltage	V _{RWM}	100	v

ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL	TEST CONDI	TIONS	VALUES	UNITS
Maximum average forward current		50 % duty cycle at T_C = 113 °C, rectangular waveform On PC board 9 mm ² island (0.013 mm thick copper pad area)		2.1	•
See fig. 4	$I_{F(AV)}$ 50 % duty cycle at T _C = 116 °C, rectangular waveform On PC board 9 mm ² island (0.013 mm thick copper pad ar		-	2	A
Maximum peak one cycle		5 µs sine or 3 µs rect. pulse	Following any rated	120	
non-repetitive surge current See fig. 6	I _{FSM}	10 ms sine or 6 ms rect. pulse	load condition and with rated V _{RRM} applied	30	A
Non-repetitive avalanche energy	E _{AS}	$T_J = 25 \text{ °C}, I_{AS} = 0.5 \text{ A}, L = 8 \text{ mH}$		1.0	mJ
Repetitive avalanche current	I _{AR}			0.5	А

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ELECTRICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CO	NDITIONS	VALUES	UNITS	
		2 A		0.91	V	
		1.5 A	T _J = 25 °C	0.85		
Maximum forward voltage drop	V _{FM} ⁽¹⁾	1 A		0.78		
See fig. 1	VFM \''	2 A		0.72		
		1.5 A	T _J = 125 °C	0.68		
		1 A		0.63		
Maximum reverse leakage current	I _{RM} ⁽¹⁾	T _J = 25 °C	$V_{\rm B}$ = Rated $V_{\rm B}$	0.1	mA	
See fig. 2	'RM \''	T _J = 125 °C	VR - naleu VR	1	ША	
Threshold voltage	V _{F(TO)}			0.52	V	
Forward slope resistance	r _t	$T_J = T_J$ maximum 78.4		78.4	mΩ	
Typical junction capacitance	CT	$V_R = 10 V_{DC}$, $T_J = 25 \text{ °C}$, test signal = 1 MHz		38	pF	
Typical series inductance	Ls	Measured lead to lead 5 mm from package body 2.0		2.0	nH	
Maximum voltage rate of change	dV/dt	Rated V _R 10 000		V/µs		

Note

 $^{(1)}\,$ Pulse width < 300 $\mu s,$ duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum junction and storage temperature range	T _J ⁽¹⁾ , T _{Stg}		-55 to +150	°C	
Maximum thermal resistance, junction to ambient	R _{thJA}	DC operation	80	°C/W	
Approvimate weight			0.07	g	
Approximate weight			0.002	oz.	
Marking device		Case style SMA (DO-214AC) (similar D-64)	2	J	

Note

 $\frac{dP_{tot}}{dT_J} < \frac{1}{R_{thJA}} \quad \text{thermal runaway condition for a diode on its own heatsink}$ (1)

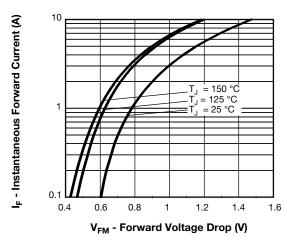


Fig. 1 - Maximum Forward Voltage Drop Characteristics

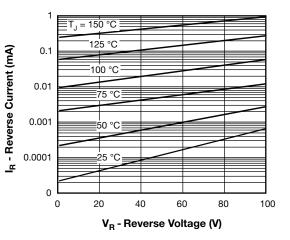


Fig. 2 - Typical Peak Reverse Current vs. Reverse Voltage

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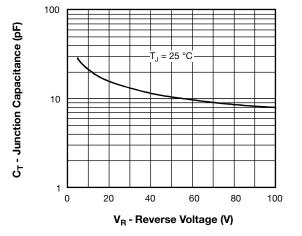
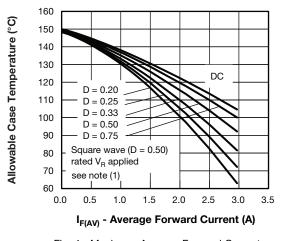
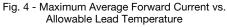


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage





Note

- ⁽¹⁾ Formula used: $T_C = T_J (Pd + Pd_{REV}) \times R_{thJC}$;
- $\begin{array}{l} \mathsf{Pd} = \mathsf{forward} \ \mathsf{power} \ \mathsf{loss} = \mathsf{I}_{\mathsf{F}(\mathsf{AV})} \times \mathsf{V}_{\mathsf{FM}} \ \mathsf{at} \ (\mathsf{I}_{\mathsf{F}(\mathsf{AV})}/\mathsf{D}) \ (\mathsf{see fig. 6}); \\ \mathsf{Pd}_{\mathsf{REV}} = \mathsf{inverse} \ \mathsf{power} \ \mathsf{loss} = \mathsf{V}_{\mathsf{R1}} \times \mathsf{I}_{\mathsf{R}} \ (\mathsf{1} \mathsf{D}); \ \mathsf{I}_{\mathsf{R}} \ \mathsf{at} \ \mathsf{V}_{\mathsf{R1}} = \mathsf{80} \ \% \ \mathsf{rated} \ \mathsf{V}_{\mathsf{R}} \end{array}$

VS-20MQ100NTRPbF

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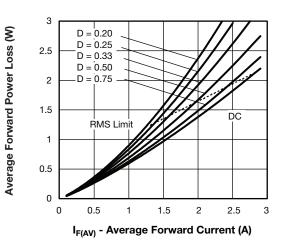


Fig. 5 - Maximum Average Forward Dissipation vs. Average Forward Current

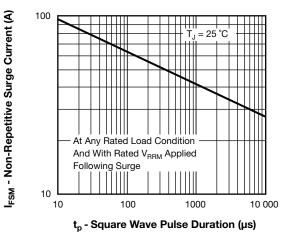


Fig. 6 - Maximum Peak Surge Forward Current vs. Pulse Duration

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ORDERING INFORMATION TABLE

Device code	VS-	20	М	Q	100	Ν	TR	PbF
	1	2	3	4	5	6	(7)	8
	1 - 2 - 3 -	Cur	nay Serr rent ratii SMA		ctors pro	oduct		
	4 -	Q =	Schottk	ky "Q" se	eries			
	5 -	Volt	tage rati	ng (100	= 100 \	/)		
	6 -	N =	new SN	ΛA				
	7 -	TR	= tape a	ind reel	(7500 p	ieces)		
	8 -	PbF	= lead	(Pb)-fre	е			

ORDERING INFORMATION (Example)						
PREFERRED P/N	PREFERRED PACKAGE CODE	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION			
VS-20MQ100NTRPbF	5AT	7500	13" diameter plastic tape and reel			

LINKS TO RELATED DOCUMENTS				
Dimensions www.vishay.com/doc?95400				
Part marking information	www.vishay.com/doc?95403			
Packaging information	www.vishay.com/doc?95404			
SPICE model	www.vishay.com/doc?97121			



Outline Dimensions

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SMA

DIMENSIONS in inches (millimeters)

DO-214AC (SMA)





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